

# SV7331

8KV ESD Protected, Wide-Supply, High-Bandwidth, Dual 4:1 Analog Switch

v0.93
SAVITECH Corporation

Savitech SV7331

## **SV7331**

### 8KV ESD Protected, Wide Supply, High-Bandwidth, Dual 4:1 Analog Switch

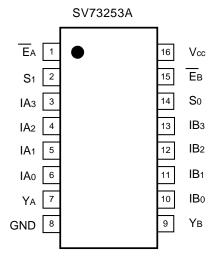
#### **Features**

- Ultra Wide Operation Voltage: +1.65V to +5.5V
- Rail to rail analog signal level
- Low In-to-Out Ron: 3.5
- Robust ESD Protection: 8KV HBM, 400V MM
- Super-low quiescent current: 0.1uA (typ)
- Loss-less transmission
- Almost no propagation delay
- Built in undershoot clamping diodes
- CMOS/TTL compatible control inputs
- PI5V331 pin compatible
- Green & Pb-free packages: QSOP-16, SOP-16 and TSSOP-16

#### Description

The SV7331 is an ultra-low Ron, low-power, high-bandwidth, high-speed rail to rail dual 4:1 analog switch. It is pin compatible with PI5V331 analog switch. With its built in undershoot clamping diodes on all control inputs and switch inputs that results in robust and reliable switching and protection.

#### **Pin Connection**



QSOP-16/SOP-16/TSSOP-16

#### **Function Table**

EA	E <sub>B</sub>	S <sub>1</sub>	S <sub>2</sub>	YA	Y <sub>B</sub>	Function
Н	Х	Х	Х	Hi-Z	Х	Disable A
Х	Н	Х	Х	Х	Hi-Z	Disable B
L	L	L	L	ιA <sub>0</sub>	ıB <sub>0</sub>	$S_1-0=0$
L	L	L	Н	ıA <sub>1</sub>	ıB <sub>1</sub>	S <sub>1</sub> -0 = 1
L	L	Н	L	ıA <sub>2</sub>	ıB <sub>2</sub>	S <sub>1</sub> -0 = 2
L	L	Н	Н	ıA <sub>3</sub>	ıB <sub>3</sub>	$S_1-0=3$

# Note:

H = Logic High L = Logic Low

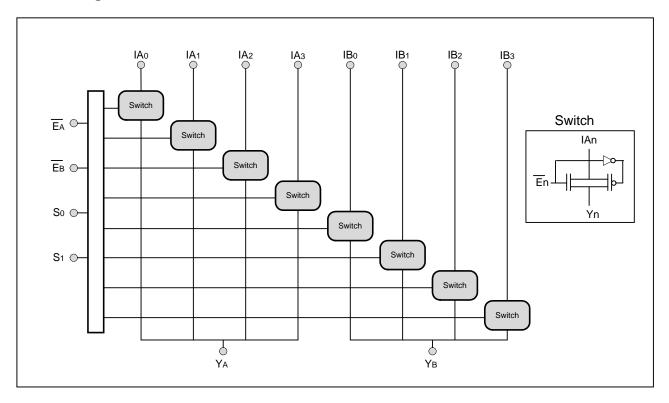
### Ordering Information

Ordering Code	Operation Range	Package	Packing
SV7331-16QP-TR2	-40°C ~ +85°C	QSOP-16	Tape & Reel, 2500pcs
SV7331-16SP-TR2	-40°C ~ +85°C	SOP-16	Tape & Reel, 2500pcs
SV7331-16TP-TR3	-40°C ~ +85°C	TSSOP-16	Tape & Reel, 3000pcs

#### **Pin Description**

PIN	DESCRIPTION	
IA <sub>N -</sub> IB <sub>N</sub>	Data Inputs	
S <sub>0</sub> ,S <sub>1</sub>	Select Inputs	
Y <sub>A</sub> ,Y <sub>B</sub>	Data outputs	
$\overline{E_A},\overline{E_B}$	Enable Inputs	
GND	Ground	
V <sub>cc</sub>	Power Supply	

### **Block Diagram**



### **Absolute Maximum Ratings**

Parameter	Value	Unit
V <sub>CC</sub> to GND, Supply Voltage,	7	V
Input Voltage	GND - 0.3 to (V <sub>CC</sub> ) +0.3	V
Storage Temperature Range	-65 to +150	°C
Continuous current through V <sub>DD</sub> or GND	100	mA
ESD Susceptibility: HBM	8000	V
ESD Susceptibility: MM	400	V

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### Caution

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SAVITECH recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### **DC Electrical Characteristics**

 $(T_A = -40^{\circ}C \text{ to } 85^{\circ}C, V_{CC} = +5V \pm 10\%)$ 

PARAMETER	Description	Test Conditions	MIN	TYP	MAX	UNITS
V <sub>IH</sub>	Input HIGH Voltage	Guaranteed Logic HIGH Level	0.6*Vcc		V <sub>CC</sub> +0.3	V
V <sub>IL</sub>	Input LOW Voltage	Guaranteed Logic LOW level	V <sub>SS</sub> -0.3		0.4*Vcc	V
I <sub>IH</sub>	Input HIGH Current	V <sub>CC</sub> = Max, V <sub>IN</sub> = V <sub>CC</sub>			±1	μΑ
I <sub>IL</sub>	Input LOW Current	V <sub>CC</sub> = Max, V <sub>IN</sub> = GND			±1	μΑ
I <sub>OZH</sub>	High Impedance Output Current	0 I <sub>n</sub> , Y <sub>n</sub> Vcc			-1	μΑ
V <sub>IK</sub>	Clamp Diode Voltage	V <sub>CC</sub> = Min., V <sub>IN</sub> = -18mA		-0.78		V
BW	-3dB Bandwidth	Signal = 0dBm		500		MHz
		V <sub>CC</sub> = 2.7V, V <sub>IN</sub> = 0V, I <sub>ON</sub> = 48mA		4.5	5.5	
		V <sub>CC</sub> = 2.7V, V <sub>IN</sub> = 2.7V, I <sub>ON</sub> = -48mA		13	15	
		V <sub>CC</sub> = 3.6V, V <sub>IN</sub> = 0V, I <sub>ON</sub> = 48mA		4.0	4.7	
5		V <sub>CC</sub> = 3.6V, V <sub>IN</sub> = 3.6V, I <sub>ON</sub> = -48mA		11	12	
R <sub>ON</sub>	Switch On-Resistance	V <sub>CC</sub> = 4.5V, V <sub>IN</sub> = 0V, I <sub>ON</sub> = 48mA		3.5	4.5	
		V <sub>CC</sub> = 4.5V, V <sub>IN</sub> = 4.5V, I <sub>ON</sub> = -48mA		10	11	
		V <sub>CC</sub> = 5.5V, V <sub>IN</sub> = 0V, I <sub>ON</sub> = 48mA		3.2	4.0	
		V <sub>CC</sub> = 5.5V, V <sub>IN</sub> = 5.5V, I <sub>ON</sub> = -48mA		8.5	9.5	
Icc	Quiescent Power Supply Current	V <sub>CC</sub> = 1.65V ~ 5.5V, VIN=GND or V <sub>CC</sub>		0.04	1	uA

#### Notes:

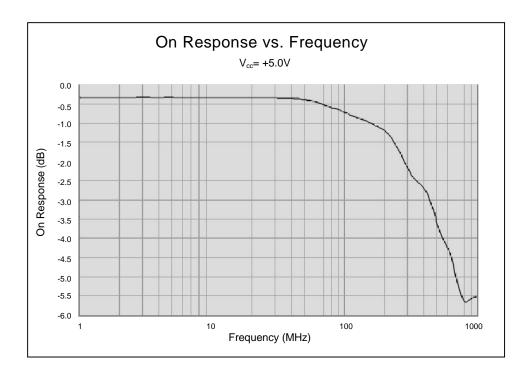
- 1. For max. or min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2.  $V_{cc} = +1.65$  to +5.5V, TA = 25°C ambient and maximum loading.
- 3. Measured by the voltage drop between  $I_n$  and  $Y_n$  pin at indicated current through the Switch On-Resistance is determined by the lower of the voltages on the two  $(I_n, Y_n)$  pins.

### **Switching Characteristics**

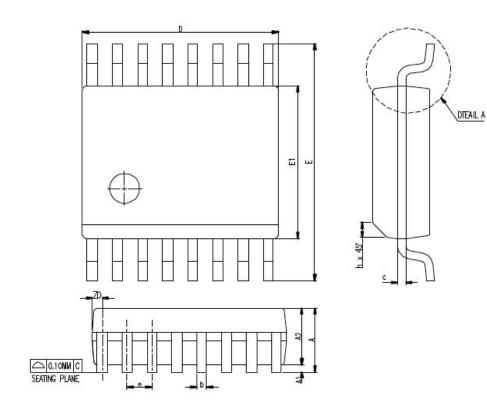
PARAMETER	Description	Test Conditions	MIN	TYP	MAX	UNITS
t <sub>IY</sub>	Propagation Delay I <sub>n</sub> to Y <sub>n</sub>			0.25		ns
t <sub>SY</sub>	Bus select time, S to Y <sub>n</sub>	C <sub>L</sub> = 20pF		3.2		ns
t <sub>PHZ</sub> , t <sub>PLZ</sub>	Bus enable time, E to Y <sub>n</sub>	$C_L = 20pF$ $R_L = 500$		6.8		ns
t <sub>PHZ</sub> , t <sub>PLZ</sub>	Bus disable time, $\overline{E}_N$ to Y			5.5		ns

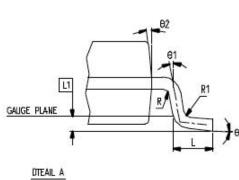
#### Notes:

- 1. For max. or min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Guaranteed by design.
- 3. The switch contributes no propagation delay other than the RC delay of the On-Resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.25ns for 20pF load. Since this time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the switch when used in a system is determined by the driving circuit on the driving side of the switch and its interactions with the load on the driven side.



### **QSOP-16 MECHANICAL DATA**



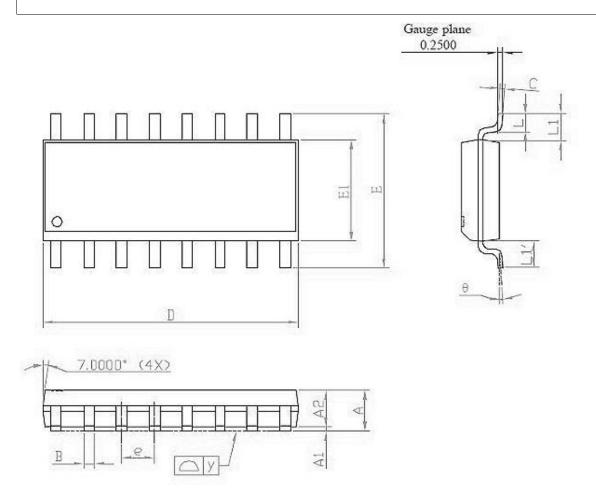


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		61		
L1		#	<u>R</u> 1	
GALIGE PLANE	}	P.		1.
1	5	-	L_	<b>≯</b> <sup>6</sup>
DTEAIL A				

- Dimension 0 does not include mold protrusions or gate burrs
   Mold protrusions and gate burrs shall not exceed 0.006 inch per side.

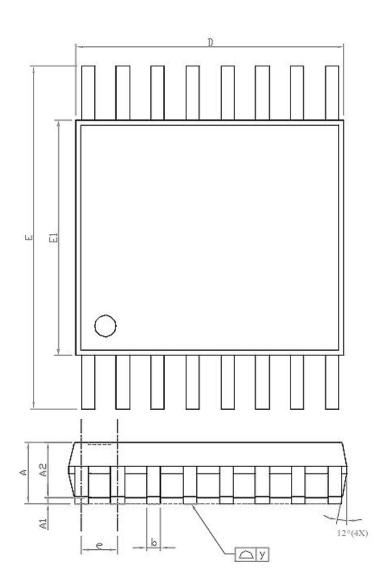
Cumhal	Dim	ension in	MM	Din	nension in	Inch
Symbol	Min.	Nom.	Max.	Min.	Nom.	Max.
Α	1.35	1.63	1.75	0.053	0.064	0.069
A1	0.10	0.15	0.25	0.004	0.006	0.010
A2			1.50			0.059
b	0.20		0.30	0.008		0.012
С	0.18		0.25	0.007		0.010
е	0.650 BASIC			0	.025 BASI	EC
D	4.80	4.90	5.00	0.189	0.193	0.197
Е	5.79	5.99	6.20	0.228	0.236	0.244
E1	3.81	3.961	3.99	0.150	0.154	0.157
L	0.41	0.635	1.27	0.016	0.025	0.050
h	0.25		0.50	0.010		0.020
L1	0.:	254 BASI	С	C	0.010 BAS	IC
ZD	C	.229 REF		0.009 REF		
R1	0.20		0.33	0.008		0.013
R	0.20			0.008		
Θ	0*		8*	0*		8*
Θ1	0*			0*		
Θ2	5*	10*	15*	5*	10*	15*
JEDEC			MO-1	37 (AB)		

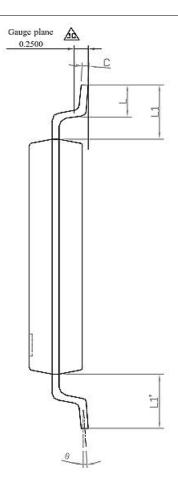
### **SOP-16 MECHANICAL DATA**



Comment of	Dim	ension in	MM	Dimension in MM Dimension		
Symbol	Min.	Nom.	Max.	Min.	Nom.	Max.
Α	1.35	1.60	1.75	0.053	0.063	0.069
A1	0.10		0.25	0.004		0.010
A2		1.45			0.057	
В	0.33		0.51	0.013		0.020
С	0.19		0.25	0.007		0.010
D	9.80		10.00	0.386		0.394
E1	3.80	3.90	4.00	0.150		0.157
е		1.27				
E	5.80	6.00	3.20	0.228		0.244
L	0.40		1.27	0.016		0.050
у			0.10			0.004
Θ	0°		8°	0°		8°
L1-L1'			0.12			0.005
L1	1.04REF				0.041REF	=

### **TSSOP-16 MECHANICAL DATA**





SYMBOLS	DIMENS	IONS IN MILLI	METERS	DIMENSIONS IN INCHES			
31 MBOLS	MIN	NOM	MAX	MIN	NOM	MAX	
A	-		1.20		<u> </u>	0.048	
A1	0.05		0.15	0.002		0.006	
A2	0.80	1.00	1.05	0.031	0.039	0.041	
ь	0.19	54000	0.30	0.007	<del></del> 3	0.012	
С	0.09		0.20	0.004	-	0.008	
D	4.90	5.00	5.10	0.193	0.197	0.201	
Е	6.20	6.40	6.60	0.244	0.252	0.260	
E1	4.30	4.40	4.50	0.169	0.173	0.177	
e		0.65		5 ( <del>50 5</del> 5 )	0.026	os si <del>ciones</del>	
L	0.45	0.60	0.75	0.018	0.024	0.030	
у	9 ( <del>)  </del>	- <del> </del>	0.10	1 1 <del>1 1</del>	<del></del> 3	0.004	
θ	0°		80	0°	3 <del>0000</del> 8	8°	
L1-L1'			0.12		<u> </u>	0.005	
L1		1.00REF			0.039REF	5 1004600	

- 1. PACKAGE BODY SIZES EXCLUDE MOLD FLASH PROTRUSIONS OR GATE BURRS

- 2. TOLERANCE ±0.1 mm UNLESS OTHERWISE SPECIFIED
  3. COPLANARITY: 0.1 mm
  4. LEAD BURR LESS THAN 5mil
  5. CONTROLLING DIMENSION IS MILLIMETER. CONVERTED INCH DIMENSIONS ARE NOT NECESSARILY EXACT.
- 6. FOLLOWED TO JEDEC MO-153

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